# Persistent Currents in Mesoscopic Hubbard Rings with Spin-Orbit Interaction

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The e ect of spin-orbit interaction on persistent currents in m esoscopic H ubbard rings threaded by an A haronov-B ohm ux is investigated putting stress on the orbital m agnetism. The non-perturbative treatment of the spin-orbit interaction developed by M eir et al. is combined with the Bethe ansatz solution to deal with this problem exactly. We not that the interplay of spin-orbit interaction and electron-electron interaction plays a crucial role, bringing about some new elects on the orbital magnetism.

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#### I. IN TRODUCTION

Persistent equilibrium current occurring in isolated mesoscopic normal metal rings penetrated by an Aharonov-Bohm (AB) ux is one of the most interesting phenomena in mesoscopic systems [1 { 9}]. It is periodic in the ux with period of a ux quantum (or halfa ux quantum) and has either diam agnetic or param agnetic sign according to di erent experim ental situations [2,3]. It has been widely accepted that spin-orbit (SO) interaction may play a crucial role in the orbitalm agnetism, e.g. the sign and the period of currents. Levy et al. have suggested that persistent currents observed by them may have a diamagnetic sign due to the e ect of strong SO interaction (although they pointed out that their determ ination contains some ambiguity) [2]. On the other hand, Altshuler et al. have claimed from therm odynam ical argum ents that the current averaged over spatial disorder is always param agnetic even in the strong SO interaction lim it [7]. Extensive studies done subsequently [10,11] have con m ed the result of Altshuler et al., and furtherm ore have revealed some interesting aspects for SO elects on the orbital magnetism. Particularly in a non-perturbative approach employed in [11] universal and nonuniversal aspects of SO e ects have been discussed, such as the reduction factor of currents, etc. The above interesting studies on SO e ects, however, have been concerned with a free electron model without electron-electron interaction. It is hence desirable to exam ine how electron-electron interaction is combined with SO interaction to a ect persistent currents in an AB geometry.

In this paper we wish to investigate the e ect of SO interaction on persistent currents in mesoscopic rings of mutually interacting electrons for the canonical ensemble. For this purpose, we study the Hubbard ring with SO interaction by combining the non-perturbative treatment of SO interaction of Meir et al. [12] with the Bethe ansatz technique [13,14]. We not that the interplay of SO interaction and electron-electron interaction produce some new e ects on the orbital magnetism. We further point out that simple reduction factors of currents due to the SO e ect are modiled in the presence of electron-electron interaction.

The organization of the paper is as follows. In Sec. II, we brie y depict how to diagonalize

the Hubbard ring with SO interaction by the Bethe ansatz method, and derive the excitation spectrum exactly. The key point is that the non-perturbative treatment of SO interaction for a non-interacting case [12] is still applicable to the Hubbard model because of local SU (2) symmetry of the Hubbard interaction. We then study, in Sec. III, the SO elects on persistent currents for case of the canonical ensemble, putting stress on the sign and the period. As is the case without SO interaction [14,15], the current shows a quite dierent behavior according to the number of electrons  $N_c$  modulo 4. We will see that upon averaging over strong SO interaction, some new elects on persistent currents are brought about by the electron-electron interaction. In Sec. IV, a possible extension to more general models including long-range interaction is presented. Sum mary and conclusion are given in Sec. V.

## II.HUBBARD RING WITH SPIN-ORBIT INTERACTION

We consider the mesoscopic Hubbard ring with SO interaction. The Hamiltonian reads

$$H = \sum_{i,j}^{X} t_{i}(S_{i}), \circ c_{i,j}^{Y} c_{i+1}, \circ + h ::+ U \sum_{i}^{X} c_{i,j}^{Y} c_{i,j}^{Y} c_{i,j}^{Y} :$$
(1)

where  $(S_i)_i$  is a matrix of SU (2), and  $t_i$  is chosen to be real for the sake of time reversal symmetry. The spin-dependent hopping matrix in (1) relects the elect of SO interaction. The interplay between the Hubbard interaction and the SO interaction makes it discult to treat the model directly. It is found, however, that one can still deal with the Ham iltonian exactly by combining the Bethe-ansatz technique with the non-perturbative approach developed for a non-interacting case [12]. The point is that the hopping term in (1) with SO interaction is cast into the diagonal form in spin space by a unitary transformation

$$U^{(i)} = U^{(1)}S_1 \qquad _i S;$$
 (2)

with the matrix U (1) being chosen appropriately. The transformation rotates the frame of spin space by a dierent angle at each site so as to produce the homogeneous hopping matrix.

An important point is that the onsite Coulomb term in (1) is invariant under such a local

spin rotation because of its SU (2) sym metry [16]. Hence one can formally gauge away SO interaction, and nd the conventional Hubbard model in the new spin space,

$$H = \sum_{\substack{i:\\i \neq i}}^{X} t_{i} c_{i;}^{Y} c_{i+1;} + h x :+ U \sum_{i}^{X} c_{i}^{Y} c_{i} c_{i}^{Y} c_{i} ;$$
(3)

where ~ denotes a transformed spin variable, and " and # label \up" and \down" spins respectively in the new spin framede ned dierently on each site. The electron is now incorporated into spin-dependent twisted boundary conditions for the eigenfunctions [12],

$$_{\sim} (N + 1) = \exp[i( + \sim )] _{\sim} (1);$$
 (4)

where  $\exp(i^{-})$  is the eigen value of  $S_1$   $_N$ ,  $S_7 = 1$  corresponds to  $\sup$  and  $\mod$  with the new spin space, and is an AB ux in unit of  $_0 = (2)$  with the ux quantum  $_0 = h = 0$ . The electron wave function acquires an additional phase shift due to SO interaction after transversing the ring. We will refer to as the SO phase shift hereinafter. It is noteworthy that the above trick to simplify the model is not speciet to the Hubbard-type interaction, but is also applicable to any interaction, including long-range type, which has local SU (2) symmetry. Such extensions will be discussed later in this paper.

In the following,  $t_n$  is assumed to be site-independent so that the lattice is regular without spatial disorder. Thus we put  $t_i = t$ . It is now straightforward to obtain the Bethe ansatz solution to the H am iltonian (3) with twisted boundary conditions (4) [17]. Following a standard method, two kinds of rapidities are necessarily introduced to diagonalize the H am iltonian. For the ring system with N sites, one thus gets the coupled transcendental equations for charge  $(p_i)$  and spin (i,j) rapidities [18,17],

$$p_{j}N = 2 I_{j} + (+) + (\sin p_{j});$$
 (5)

with (p) =  $2\tan^{-1}(4tp=U)$ , where the number of total electrons (down-spin electrons) is  $N_c$  ( $N_s$ ). The quantum numbers  $I_j$  and J are integers (or half integers), which specify charge and spin excitations. The total energy is given in terms of the charge rapidity,  $E = 2t^{\frac{P}{N_c}} \sum_{j=1}^{N_c} \cos p_j$ . Note that the e ect of SO interaction electively shifts the quantum numbers  $I_j$  and J whereas that of Coulomb interaction appears via the two-body phase shift function (k).

Let us now consider the e ect of SO interaction on the energy spectrum. Applying a machinery developed by W oynarovich [13] to Eqs.(5) and (6), one can readily classify the excitation spectrum including the nite-size corrections which are important for the mesoscopic Hubbard ring. For the xed number of electrons, low-lying excitations are specified by two kinds of quantum numbers D  $_{\rm c}$  and D  $_{\rm s}$ , which respectively carry the momentum  $4k_{\rm F}$  D  $_{\rm c}$  (charge current) and  $2k_{\rm F}$  D  $_{\rm s}$  (spin current), where  $k_{\rm F}$  is the Fermi momentum. The excitation spectrum including SO interaction is written down as [13,19],

E(;) 
$$E_0 = \frac{4 \text{ V}_c}{\text{N}} \text{K} \quad D_c + \frac{D_s}{2} + \frac{D_s}{2} + \frac{V_s}{\text{N}} D_s - \frac{2}{3};$$
 (7)

where  $v_c$  and  $v_s$  are the velocities of charge and spin excitations respectively, and K is the critical exponent for the  $4k_F$  oscillating piece of charge correlation functions [13]. For the Hubbard model 1=2 K 1 [19{21]. These three fundamental quantities characterize the Luttinger liquid properties of interacting electrons completely [22], which can be straightforwardly evaluated using the Bethe-ansatz integral equation resulting from (5) and (6) [13,19{21}. For a given number of electrons it is necessary to not the lowest energy state correctly in order to derive the expression for currents. It is crucial for this purpose to notice that the quantum numbers D  $_c$  and D  $_s$  respect the following selection rule rejecting the Ferm i statistics [13],

$$D_c = \frac{N_c + N_s + 1}{2}$$
 (m od 1);

$$D_{s} = \frac{N_{c}}{2}$$
 (m od 1): (9)

We note that in the absence of SO interaction, the above spectrum has been analyzed by Yu and Fow ler to study persistent currents [14].

## III. EFFECTS OF SPIN -ORBIT INTERACTION ON PERSISTENT CURRENTS

We now study the e ects of SO interaction on persistent equilibrium currents in the Hubbard ring. Since we wish to discuss the magnetism for the canonical ensemble with the xed number of electrons, let us brie y sum marize som e results known for the canonical ensemble. The property of the orbital magnetism is sensitive to the number of ferm ions carrying the currents [23,24]. For example, a free electron model without SO interaction the orbital magnetism depends on the total number of electrons N c modulo 4; i.e., the ground state is diamagnetic for  $N_c = 4n + 2$ , paramagnetic for  $N_c = 4n$  with period of a ux quantum, and param agnetic with period of half a ux quantum for  $N_c = 4n + 1$ ; 4n + 3 [15]. The results are slightly modied in the presence of electron-electron interaction as shown for the 1D Hubbard model [14,25]. For instance the paramagnetic state for N  $_{\rm c}=4{\rm n}$  is altered to a diam agnetic one by electron-electron interaction except near half lling (one electron per lattice site). In the presence of SO interaction, further modi cations are expected to occur in the orbital magnetism due to the interplay of SO interaction and electron-electron interaction. In particular we will see below that for a certain parameter regime of the interaction strength, the param agnetic state is stabilized for N  $_{\rm c}$  = 4n + 2 in contrast to the case without SO interaction for which the ground state is always diam agnetic.

In order to clearly see what is going on, we set study the case of 4n + 2 in detail, and mention the other cases later in this section. It may be plausible to introduce here an important key quantity  $v_c K = v_s$ , which will be helpful for following arguments. For noninteracting electrons,  $v_c K = v_s = 1$  for any electron concentrations because  $v_c = v_s$  and K = 1, whereas in correlated cases of  $V \in 0$  the value of  $v_c K = v_s$  ranges from 0 to 1 depending on the interaction strength as well as electron concentrations. We show  $v_c K = v_s$  as a function of electron concentrations in Fig. 1. Roughly speaking, one can see from

this quantity whether the SO electimary be enhanced or suppressed by the electron-electron interaction. For example, the SO elect is suppressed for  $v_c K = v_s > 1$ , whereas it is enhanced for  $v_c K = v_s < 1$ .

A .Persistent currents for N 
$$_{\rm C}$$
 = 4n + 2 (N  $_{\rm S}$  = 2n + 1)

It is seen from Eqs.(8) and (9) that the selection rule for the quantum numbers in this case is D  $_{\rm c}=0$  (m od 1) and D  $_{\rm s}=0$  (m od 1), which implies that the ground state in the absence of SO interaction is diamagnetic around =0 [20,25,26]. Turning on an AB ux, there occur two dierent situations according to the magnitude of  $v_{\rm c}K=v_{\rm s}$ . It is straightforward to derive the persistent current I=0 (E=0 from Eqs. (7). For  $v_{\rm c}K=v_{\rm s}=1$ , the current takes the form [14]

$$I = \frac{\frac{V_{c}K}{N}}{\frac{V_{c}K}{N}} ( )$$

$$c < < c$$

$$v_{c}K$$

$$v_{c}K$$

$$N$$

$$c < c$$

w here

$$_{c} = \frac{1}{2} + \frac{v_{s}}{2K v_{c}} + \frac{v_{s}}{K v_{c}}$$
: (11)

One can see that the SO phase shift—simply alters the critical value— $_{\rm c}$  of the AB—ux, and the diam agnetic nature around = 0 is not modi ed by SO interaction. From Eq.(11) it is explicitly seen that the e ect of SO interaction is suppressed as the value of  $v_{\rm c}K$  = $v_{\rm s}$  increases. Such cases with  $v_{\rm c}K$  = $v_{\rm s}$  1 realize at lower electron concentrations for U  $\in$  0, as seen from Fig. 1. It is instructive to point out here that for = =2 the e ects of electron-electron interaction disapear in Eq.(11), and hence the period is halved as has been known for a free electron model [12]. An alternative expression of Eq.(10) in Fourier series expansion is found to be more convenient for following discussions,

$$I() = \frac{X}{N} \frac{v_c K}{n} \frac{(1)^n}{n} \cos n \frac{1}{2} \frac{v_s}{2K v_c} + \frac{v_s}{K v_c} \sin (n); \qquad (12)$$

In contrast to the above case, the expression for currents in the case of  $v_c K = v_s < 1$  depends on the value of the SO phase shift . For 0  $< K v_c = 2v_s + = 2$  the current is given by the same expression as Eq.(10), whereas for  $K v_c = 2v_s + = 2$  it is changed to

$$I = \begin{cases} \frac{8}{N} & \frac{V_{c}K}{N} (+) & 0 \\ \frac{8}{N} & \frac{V_{c}K}{N} (-) & 0 < \vdots \end{cases}$$
 (13)

This is cast into an alternative formula in the Fourier series expansion as

$$I() = \sum_{n=1}^{X} \frac{v_{c}K}{N n} \sin(n) :$$
 (14)

One can see from Eq.(13) that the current has a paramagnetic sign around = 0. This change in sign is due to the interplay of the SO interaction and electron-electron interaction, which still plays a crucial role upon averaging over the strong SO interaction (see below).

## B. Strong SO interaction lim it

We have seen that the SO phase shift—crucially modi es the characteristic behavior of the orbital magnetism—in correlated electrons. The quantity—is to be determined in the range [0; ] for a given scattering process by SO interaction. For example when the scattering length of SO interaction would be comparable to the length of the ring, the value of—could be around—2, which results in the period of currents halved by the elect of the SO interaction as seen from (12). In more general cases when the length of the ring may be much larger than the scattering length, one has to take into account all possible rotations in spin space due to SO scattering. Such a limit is referred to as the strong SO interaction limit [11,12]. Since the SO phase shift—is directly related to the rotation angle in spin space, one should average currents over—from 0 to—with the weight  $\sin^2$ —[11,27]. The Fourier transformed formulae of currents are more convenient to carry out the average. U sing Eqs.(12) and (14), we thus derive the expression for persistent currents in the strong SO interaction limit. In the case of  $v_c K = v_s = 1$  (low electron densities), we get

$$I() = \frac{X}{m} \frac{v_c K}{2^{-2} N} \frac{v_c K}{v_s m} + \frac{v_s v_c K m}{4 v_c^2 K^{-2} 4 v_s^2 m^{-2}} \frac{(1)^m}{m} \sin m \frac{v_s}{v_c K} \sin (2m); \qquad (15)$$

It is seen that all the odd harm onics are dropped, and hence the period is reduced to half a ux quantum. In contrast to a free electron case in which only harm onics n=0; 2 remain and the harm onics n=2 gives a diam agnetic sign change with a reduction factor l=2 [11], all higher even harm onics survive in the correlated case. However it is found that the ground state is still diam agnetic around l=0. To see this more explicitly we evaluate the sum of the coe cient by Fourier transform ation:

$$\frac{X}{m} \frac{v_{c}K}{m v_{s}} + \frac{v_{s}v_{s}K m}{4v_{c}^{2}K^{2} 4v_{s}^{2}m^{2}} (1)^{m} \sin \frac{v_{s}m}{v_{c}K} = \frac{1}{2};$$
 (16)

which results in the diam agnetic current I() =  $(v_cK = N)$ . Note that this is exactly same as the current without SO interaction. Hence we can conclude that in case of  $v_cK = v_s$  1, the behavior of currents around = 0 is not modified by the SO exects even in the strong interaction limit. This is because the SO interaction can a extitle occupation of energy levels only when there exists a nite AB ux in the system.

The situations are somewhat dierent for  $v_c K = v_s < 1$  (close to half lling). There are both diam agnetic and param agnetic contributions to currents depending on . The current average over the strong SO interaction is thus given by

$$I() = \frac{x}{n} \frac{v_c K}{2^{-2} N n} \frac{v_s^2 n^2}{4 v_c^2 K^{-2} v_s^2 n^2} \sin \frac{v_c K}{v_s} + \frac{8 v_c^3 K^{-3}}{v_s n (4 v_c^2 K^{-2} v_s^2 n^2)} \sin \frac{n}{2} + \frac{n v_s}{2 v_c K} + \frac{v_c K}{v_s} \sin (n);$$

$$(17)$$

The period is not halved upon averaging over in this case. For small positive with  $1=3 < v_c K = v_s < 1$ , one can perform the inverse Fourier transform ation to get for ! 0,

$$I() = \frac{2v_{c}K}{N} \frac{v_{c}K}{v_{s}} \cos \frac{v_{c}K}{v_{s}} + \frac{v_{s}}{v_{s}} \frac{v_{c}K}{v_{s}} \frac{1}{2} \frac{v_{c}K}{v_{s}} \sin \frac{v_{c}K}{v_{s}};$$
(18)

which has a param agnetic sign. Since param agnetic contributions to the current averaged over increase compared with diamagnetic ones when  $v_c K = v_s$  is decreased, we can say that

the current for 0  $v_cK = v_s < 1$  always shows a param agnetic sign around = 0. We would like to stress here that this param agnetic state realizes as a consequence of the interplay of SO interaction and electron-electron interaction, and should not appear if either of the two is absent.

We have computed persistent currents using the formulae (15) and (17) together with the Bethe equations for  $v_c$ ,  $v_s$ , and K [13]. In Figs. 2 and 3, persistent currents in the strong SO limit are shown as a function of the AB ux for two dierent cases.

## C.Reduction factors in currents

Here we make a brief comment on reduction factors in persistent currents by the SO e ects. A coording to Meir et al. [12] and Entin-Wohlman et al. [11], reduction factors due to the SO interaction are written in a simple and universal form for a noninteracting model with even number of electrons. An essence of their idea is that the persistent current I() in the presence of SO interaction can be expressed in the form

$$I() = I_0(+) + I_0()$$
 (19)

where  $I_0$  is the current per each spin component without SO interaction. This leads to universal reduction factors in the form of Fourier expansion [11,12],

$$I() = \int_{n}^{X} \cos(n) a_{h} \sin(n)$$
 (20)

with  $a_n$  being the Fourier coe cients for the case without SO interaction. One can see that the reduction factor  $\cos(n)$  depends only on the SO phase shift. This expression leads to a rather  $\sin p$  le result that upon averaging in the strong SO  $\lim it$ , the current is reduced by a factor of 1/2, and the uctuations by a factor 1/4 [11,12]. For interacting electrons, however, it is seen that the SO phase shift should not appear in a  $\sin p$  le form of . It is instead combined with a factor of  $v_c$  K  $=v_s$  rejecting the electron correlation ejects. Thus in the presence of electron-electron interaction, the reduction factors follow from Eqs.(12),

$$\cos n - \frac{v_s}{2} - \frac{v_s}{2v_c K} + \frac{v_s}{v_c K} = \cos n - \frac{v_s}{2} - \frac{v_s}{2v_c K}$$
; (21)

for  $v_c K = v_s$  1. For  $v_c K = v_s < 1$  we can not de ne the reduction factor in such a simple form, as seen from Eqs.(17). So, the above remarkable properties obtained for the SO e ects based on a free electron model are changed when the electron-electron interaction is introduced. To avoid confusions we would like to mention that the present nonuniversal results may not be contradicted with the universal reduction factor of currents expected in disordered system [10,11,27{30}]. In such cases the average over disorder may play an essential role, which has not been taken into account in the present calculation.

## D.Electron-number dependence

We have been concerned so far with the case of  $N_c = 4n + 2$ . As mentioned before the results are sensitively dependent on the number of electrons. Here we sum marize the results for other cases. The calculation can be performed in parallel to the above example of  $N_c = 4n + 2$ .

(a) N<sub>c</sub> = 4n (N<sub>s</sub> = 2n). In this case the selection rule for the quantum numbers reads, D<sub>c</sub> = 1=2 (m od 1) and D<sub>s</sub> = 0 (m od 1). For  $v_c K = v_s$  1 the persistent current in the Fourier transformed form is then given by

I() = 
$$\frac{X}{N} \frac{v_c K}{N n} \cos n \frac{1}{2} \frac{v_s}{2v_c K} + \frac{v_s}{v_c K} \sin (n);$$
 (22)

which shows a diam agnetic sign around = 0. In the case of  $v_c K = v_s < 1$ , where only the param agnetic state realizes without SO interaction, the expression is the same as Eq.(22) for =2  $v_c K = 2v_s <$ , while Eq.(14) for 0 =2  $v_c K = 2v_s$ . Thus the paramagnetic state near the metal-insulator transition (half-lling) is changed to a diam agnetic one by SO interaction for =2  $v_c K = 2v_s <$ . It is remarkable, however, that in the strong SO interaction lim it we obtain exactly the same results in currents as for the case of  $N_c = 4n + 2$  upon averaging over all possible phases (see Figs. 2 and 3).

We can hence sum marize the results for the even number of electrons as follows; the ground state is always diam agnetic for  $v_c K = v_s - 1$  (low electron densities) in the strong SO limit, whereas for  $v_c K = v_s < 1$  (near the metal-insulator transition point) the paramagnetic state is stabilized not only for  $N_c = 4n$  but also for  $N_c = 4n + 2$  as a result of the SO elects.

(b) 0 dd case ( $N_c = 4n + 1; 4n + 3$ ). We rst consider the case for  $N_c = 4n + 3$ . Since Eq.(7) holds only for the case with  $N_\pi$   $N_\#$ , the roles of \up" spin and \down" spin for > 0 are interchanged for < 0 in Eq.(7). Thus the result for < 0 in the case of odd number of electrons can be deduced from that for > 0 by changing ! . Noting the selection rule  $D_c = 1=2$  (m od 1) and  $D_s = 1=2$  (m od 1) for > 0, the current in the ground state is now given by

$$I = \begin{cases} \frac{8}{8} & \frac{V_{c}K}{N} + \frac{1}{2} \\ \frac{8}{N} & \frac{V_{c}K}{N} & \frac{1}{2} \end{cases}$$
 (23)

which has a period of halfa ux quantum, and exhibits a param agnetic sign around = 0. It should be noted that the above expression is independent of , and hence there are not any modi cations due to SO interaction. The elect of SO interaction indeed appears in the next order corrections in 1=N, which are not taken into account in our formulation. For a non-interacting case the next-order corrections have been evaluated by Entin-W ohlm an et al., resulting in a small shift of energy minima from = 2 to  $= [(1 + 1 = N_c) = 2 = N_c]$  [11,31], which may be actually neglected in mesoscopic rings. We note that for another odd case of  $N_c = 4n + 1$ , we get the exactly same results of currents as for  $N_c = 4n + 3$ .

In sum m ary we can say that characteristic properties of persistent currents in the strong SO lim it are classified by the parity of the electron number even for correlated electron systems.

### IV.EXTENSION TO MORE GENERAL MODELS

In the Hubbard model the electron-electron interaction is assumed to be short-ranged (on-site), which in turn enables us to treat the model exactly. In more general cases, however,

e ective interaction would be of long-range type, since the screening e ect of the Coulomb interaction m ay become less e ective for mesoscopic metallic rings. In such cases it is quite dicult to get the energy spectrum exactly. So it is desirable to not a possible way to extend our analysis to more general cases including long-range interaction. We wish to brie y depict a simple idea how to treat such cases.

We recall here a trick used to simplify the Hubbard model with SO interaction, i.e. a unitary transform ation which incorporates the SO interaction into the boundary e ects (2). Note that this technique is still applicable to more general long-range interactions so long as they retain local SU (2) symmetry. Such a local SU (2) symmetry for interaction may be expected to hold in ordinary cases, such as partially screened C oulomb interaction, etc. The remaining problem is then how to obtain the expression for the low-energy spectrum like Eq.(7) including the SO e ect and the AB ux. To this end the bosonization technique may be useful [32,33,20,22] because it can formally describe low-energy states even for non-integrable systems. The bosonization scheme has been previously used by Loss to discuss persistent currents for a spinless ferm ion system [24].

Following a standard technique in bosonization [32,33], we now discuss how the SO e ect on currents can be treated in nonintegrable systems. We do not have to specify an explicit form of interaction here, but only assume the interaction V(r) to be invariant under local SU(2) transformations. In general, low-energy gapless states of 1D metallic electron systems compose of two independent Luttinger liquids [22] corresponding to charge and spin degrees of freedom [19{21}. Hence the system is described by the sum of two Gaussian models with conformal charge c=1.

Let us now introduce the boson elds for spin and charge degrees of freedom. It is found that the spin-dependent twisted boundary conditions (2) due to an AB ux and SO interaction are incorporated into boson phase elds as [22,24]

$$= \sum_{k \in 0}^{X} \frac{1}{2Lk} e^{ikx} [a_k^y; + a_k; ] + o; + M \frac{x}{L};$$
 (24)

$$= \sum_{k \in 0}^{X} \frac{1}{2Lk} e^{ikx} [a_{k;}^{Y} + a_{k;}] + 0; + M \frac{x}{L};$$
 (25)

$$= \frac{x}{2Lk} \frac{1}{2Lk} \operatorname{sgn}(k) e^{ikx} \left[ a_k^y, a_k, \right] + 0, + J + \frac{p}{2} - \frac{L}{L} x + \frac{L}{2};$$
 (26)

$$= \sum_{k \in 0}^{X} \frac{1}{2Lk} \operatorname{sgn}(k) e^{ikx} [a_{k}^{y}; \quad a_{k}; ] + o_{k} + J + P - \frac{L}{2} \times \frac{L}{2};$$
 (27)

where  $a_k$ ;  $(a_k^y)$  and  $a_k$ ;  $(a_k^y)$  are boson annihilation (creation) operators for charge and spin densities, respectively, and M (M ) and J (J ) are the charge (spin) number and the charge (spin) current, respectively, which are de ned by M = (M " + M #) =  $\overline{2}$ , M = (M " M #) =  $\overline{2}$ , J = (J " + J #) =  $\overline{2}$ , and J = (J " J #) =  $\overline{2}$ . We note here that M " (#) and J " (#) describe topological excitations introduced by H aldane [22]. They satisfy the selection rules, (1) N 0s+1 = (1) M s+Js, where s = ", # and N 0" (#) is the total number of up (down) spins. 0; and 0; are conjugate variables of J and M, respectively.

Using the above phase elds we can write down the low-energy elective Hamiltonian, from which the persistent current directly follows, as long as the system belongs to the universality class of Luttinger liquids. The energy spectrum of the elective Hamiltonian with nite-size correction terms reads [22]

E() 
$$E_0 = \frac{1}{2L} v_M M^2 + v_J J + \frac{p_2}{2} + v_M M^2 + v_J J + \frac{p_2}{2}$$
; (28)

where  $v_M$  and  $v_J$  ( = , ) are Luttinger liquid parameters describing the velocity of excitations. It is to be noted that the e ect of electron-electron interaction V (r) is only to renormalize these parameters. The ground state is given by the condition, M = M = 0, i.e.  $M_T = M_T = 0$ . Thus using the selection rules mentioned above we obtain the topological constraints for  $J_T$  and  $J_T$ : (1)  $J_T$  even,  $J_T$  even for  $N_C = 4n + 2$ , (2)  $J_T$  odd,  $J_T$  odd for  $N_C = 4n$ , (3)  $J_T$  odd,  $J_T$  even (and vice versa) for  $N_C = 4n + 3$ , (4)  $J_T$  even,  $J_T$  odd (and vice versa) for  $J_T$  and  $J_T$  even (and vice versa) for  $J_T$  even,  $J_T$  odd that the energy (28) with these topological constraints is equivalent to Eq.(7), and  $J_T$  and  $J_T$  correspond to  $J_T = 2$  and  $J_T$  expectively.

U sing Eq.(28) and the above topological constraints, we can obtain the persistent current, and discuss its sign and period quite similarly to the case for the Hubbard ring. Therefore all the expressions derived in the previous section can be directly applied to the present case by regarding  $v_c K = v_s$  as a free parameter to be determined. In order to determine the parameter, we generally need input data from another microscopic calculations, e.g. numerical diagonalization. We note that several elegant techniques to get the Luttinger liquid parameters numerically for nonintegrable systems have been already developed [22,20], which will be helpful for us to evaluate the persistent currents explicitly.

## V.SUMMARY

In this paper we have discussed the e ects of SO interaction on persistent currents in the mesoscopic Hubbard ring. We have investigated the problem exactly combining the Betheansatz solution with a unitary transformation which incorporates the SO e ects into spin-dependent twisted boundary conditions. It has been shown that characteristic properties of the orbital magnetism in the Hubbard ring are classified according to the value of  $v_c K = v_s$  and the number of electrons modulo 4. In particular, we have demonstrated that  $v_c K = v_s$  is an important key quantity to see whether the SO e ects are enhanced or suppressed by the electron-electron interaction.

In the strong SO interaction lim it it has been found that the form ula obtained for currents is classi ed by the parity of the electron number. For the even number of electrons, the ground state is diam agnetic with period of halfa ux quantum for  $v_c K = v_s - 1$  (low electron densities), and param agnetic with period of a ux quantum for  $v_c K = v_s < 1$  (close to half lling). In particular the param agnetic state for  $v_c K = v_s < 1$  is realized by a combined e ect arising from the interplay of SO interaction and electron-electron interaction. In the Hubbard model, the condition  $v_c K = v_s < 1$  is satisted near half lling which in plies that the system would be close to the M ott insulator. Therefore such a novel phenomenon for  $v_c K = v_s < 1$  is expected in general to occur for interacting electrons in a metallic phase close

to the M ott insulator. In contrast to the even case, the ground state for the odd number of electrons is found to be always param agnetic with period of half a ux quantum, which is not a exted by SO interaction as long as the corrections up to the order of O (1=N) are concerned.

In conclusion the e ect of SO interaction together with electron-electron interaction gives rise to a novel and qualitative change in the orbital magnetism for 1D interacting electron systems. There remain several important problems to be investigated. For example we have not considered the e ect of disorder in this paper, which would induce interesting phenomena together with the SO e ects as well as with the correlation e ects. Furtherm ore an extension of the theory to multichannel cases is desirable to confront the results with various experiments. These problems are now under consideration.

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# FIGURES

FIG.1.

Plots of  $v_c K = v_s$  as a function of electron densities n for the Hubbard model. The half lling corresponds to n=1.

FIG.2.

Persistent currents plotted against =2 for U=t=4 and n=0.65 ( $v_cK=v_s=1.32$ ) in the case of even number of electrons. The current normalized by t=N is shown.

FIG.3.

Persistent currents plotted against =2 for U=t=4 and n=0.95 ( $v_cK=v_s=0.58$ ) in the case of even number of electrons. The current normalized by t=N is shown.